NSN 5961-01-075-2796

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-075-2796 **Inclosure Material:** Metal **Overall Length:** 0.460 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.187 inches **Thread Size:** 0.112 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 12.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Thread Series Designator:** Unc **Terminal Type And Quantity:** 1 turret and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

Fiig: A110a0